

# MC68LK332

## *Technical Supplement*

## **16.78 MHz Electrical Characteristics**

Devices in the 68300 Modular Microcontroller Family are built up from a selection of standard functional modules. The MC68LK332 incorporates a central processing unit (CPU32), a system integration module (SIM), a queued serial module (QSM), a time processor unit (TPU), and a 2 K-byte static RAM module with TPU emulation capability (TPURAM). The functionality of the MC68LK332 is enhanced from the MC68L332 to include an operational PLL.

This publication contains a new electrical characteristics appendix for the MC68LK332 to be used in conjunction with the *MC68332 User's Manual* (MC68332UM/AD).

# PRELIMINARY



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Table 1 Maximum Ratings

| Num | Rating                                                                                                                                                            | Symbol    | Value                        | Unit               |
|-----|-------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------|------------------------------|--------------------|
| 1   | Supply Voltage <sup>1, 2, 3</sup>                                                                                                                                 | $V_{DD}$  | – 0.3 to + 6.5               | V                  |
| 2   | Input Voltage <sup>1, 2, 3, 4, 5, 7</sup>                                                                                                                         | $V_{IN}$  | – 0.3 to + 6.5               | V                  |
| 3   | Instantaneous Maximum Current<br>Single Pin Limit (all pins) <sup>1, 3, 5, 6</sup>                                                                                | $I_D$     | 25                           | mA                 |
| 4   | Operating Maximum Current<br>Digital Input Disruptive Current <sup>3, 5, 6, 7, 8</sup><br>$V_{NEGCLMAP} \cong -0.3\text{ V}$<br>$V_{POSCLAMP} \cong V_{DD} + 0.3$ | $I_{id}$  | – 500 to 500                 | $\mu\text{A}$      |
| 5   | Operating Temperature Range<br>C Suffix                                                                                                                           | $T_A$     | $T_L$ to $T_H$<br>– 40 to 85 | $^{\circ}\text{C}$ |
| 6   | Storage Temperature Range                                                                                                                                         | $T_{stg}$ | – 55 to 150                  | $^{\circ}\text{C}$ |

## NOTES:

1. Permanent damage can occur if maximum ratings are exceeded. Exposure to voltages or currents in excess of recommended values affects device reliability. Device modules may not operate normally while being exposed to electrical extremes.
2. Although sections of the device contain circuitry to protect against damage from high static voltages or electrical fields, take normal precautions to avoid exposure to voltages higher than maximum-rated voltages.
3. This parameter is periodically sampled rather than 100% tested.
4. All pins except TSC.
5. Input must be current limited to the value specified. To determine the value of the required current-limiting resistor, calculate resistance values for positive and negative clamp voltages, then use the larger of the two values.
6. Power supply must maintain regulation within operating  $V_{DD}$  range during instantaneous and operating maximum current.
7. All functional non-supply pins are internally clamped to  $V_{SS}$ . All functional pins except EXTAL and XFC are internally clamped to  $V_{DD}$ .
8. Total input current for all digital input-only and all digital input/output pins must not exceed 10 mA. Exceeding this limit can cause disruption of normal operation.

Table 2 MC68LK332 Typical Ratings

| Num | Rating                                                                                                                                   | Symbol      | Value                   | Unit                 |
|-----|------------------------------------------------------------------------------------------------------------------------------------------|-------------|-------------------------|----------------------|
| 1   | Supply Voltage                                                                                                                           | $V_{DD}$    | 3.3                     | V                    |
| 2   | Operating Temperature                                                                                                                    | $T_A$       | 25                      | °C                   |
| 3   | $V_{DD}$ Supply Current<br>RUN<br>LPSTOP, VCO off<br>LPSTOP, External clock, max $f_{sys}$                                               | $I_{DD}$    | 45<br>125<br>1.0        | mA<br>μA<br>mA       |
| 4   | Clock Synthesizer Operating Voltage                                                                                                      | $V_{DDSYN}$ | 3.3                     | V                    |
| 5   | $V_{DDSYN}$ Supply Current<br>VCO on, maximum $f_{sys}$<br>External Clock, maximum $f_{sys}$<br>LPSTOP, VCO off<br>$V_{DD}$ powered down | $I_{DDSYN}$ | 1.0<br>2.0<br>100<br>50 | mA<br>mA<br>μA<br>μA |
| 6   | RAM Standby Current<br>Normal RAM operation<br>Standby operation                                                                         | $I_{SB}$    | 3.0<br>10               | μA<br>μA             |
| 7   | Power Dissipation                                                                                                                        | $P_D$       | 148.0                   | mW                   |

Table 3 Thermal Characteristics

| Num | Rating                                                                               | Symbol        | Value    | Unit |
|-----|--------------------------------------------------------------------------------------|---------------|----------|------|
| 1   | Thermal Resistance<br>Plastic 132-Pin Surface Mount<br>Plastic 144-Pin Surface Mount | $\Theta_{JA}$ | 38<br>49 | °C/W |

The average chip-junction temperature ( $T_J$ ) in C can be obtained from:

$$T_J = T_A + (P_D \times \Theta_{JA}) \quad (1)$$

where:

$T_A$  = Ambient Temperature, °C

$\Theta_{JA}$  = Package Thermal Resistance, Junction-to-Ambient, °C/W

$P_D$  =  $P_{INT} + P_{I/O}$

$P_{INT}$  =  $I_{DD} \times V_{DD}$ , Watts — Chip Internal Power

$P_{I/O}$  = Power Dissipation on Input and Output Pins — User Determined

For most applications  $P_{I/O} < P_{INT}$  and can be neglected. An approximate relationship between  $P_D$  and  $T_J$  (if  $P_{I/O}$  is neglected) is:

$$P_D = K + (T_J + 273^\circ\text{C}) \quad (2)$$

Solving equations 1 and 2 for K gives:

$$K = P_D \times (T_A + 273^\circ\text{C}) + \Theta_{JA} \times P_D^2 \quad (3)$$

where K is a constant pertaining to the particular part. K can be determined from equation (3) by measuring  $P_D$  (at equilibrium) for a known  $T_A$ . Using this value of K, the values of  $P_D$  and  $T_J$  can be obtained by solving equations (1) and (2) iteratively for any value of  $T_A$ .

Table 4 Clock Control Timing

(V<sub>DD</sub> and V<sub>DDSYN</sub> = 3.0 to 3.6 Vdc, V<sub>SS</sub> = 0 Vdc, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>)

| Num | Characteristic                                                                                   | Symbol           | Min                        | Max                      | Unit |
|-----|--------------------------------------------------------------------------------------------------|------------------|----------------------------|--------------------------|------|
| 1   | PLL Reference Frequency Range                                                                    | f <sub>ref</sub> | 20                         | 50                       | kHz  |
| 2   | System Frequency <sup>1</sup><br>On-Chip PLL System Frequency<br>External Clock Operation        | f <sub>sys</sub> | 4(f <sub>ref</sub> )<br>dc | 16.78<br>16.78           | MHz  |
| 3   | PLL Lock Time <sup>2, 3, 4, 5</sup>                                                              | t <sub>pll</sub> | —                          | 20                       | ms   |
| 4   | VCO Frequency <sup>6</sup>                                                                       | f <sub>VCO</sub> | —                          | 2 (f <sub>sys</sub> max) | MHz  |
| 5   | CLKOUT Jitter <sup>2, 3, 4, 7</sup><br>Short term (5 μs interval)<br>Long term (500 μs interval) | J <sub>clk</sub> | −1.0<br>−0.5               | 1.0<br>0.5               | %    |

## NOTES:

1. All internal registers retain data at 0 Hz.
2. This parameter is periodically sampled rather than 100% tested.
3. Assumes that a low-leakage external filter network is used to condition clock synthesizer input voltage. Total external resistance from the XFC pin due to external leakage must be greater than 15 MΩ to guarantee this specification. Filter network geometry can vary depending upon operating environment.
4. Proper layout procedures must be followed to achieve specifications.
5. Assumes that stable V<sub>DDSYN</sub> is applied, and that the crystal oscillator is stable. Lock time is measured from the time V<sub>DD</sub> and V<sub>DDSYN</sub> are valid until  $\overline{\text{RESET}}$  is released. This specification also applies to the period required for PLL lock after changing the W and Y frequency control bits in the synthesizer control register (SYNCR) while the PLL is running, and to the period required for the clock to lock after LPSTOP.
6. Internal VCO frequency (f<sub>VCO</sub>) is determined by SYNCR W and Y bit values. The SYNCR X bit controls a divide-by-two circuit that is not in the synthesizer feedback loop. When X = 0, the divider is enabled, and f<sub>sys</sub> = f<sub>VCO</sub> ÷ 4. When X = 1, the divider is disabled, and f<sub>sys</sub> = f<sub>VCO</sub> ÷ 2. X must equal one when operating at maximum specified f<sub>sys</sub>.
7. Jitter is the average deviation from the programmed frequency measured over the specified interval at maximum f<sub>sys</sub>. Measurements are made with the device powered by filtered supplies and clocked by a stable external clock signal. Noise injected into the PLL circuitry via V<sub>DDSYN</sub> and V<sub>SS</sub> and variation in crystal oscillator frequency increase the J<sub>clk</sub> percentage for a given interval. When jitter is a critical constraint on control system operation, this parameter should be measured during functional testing of the final system.

**Table 5 16.78 MHz DC Characteristics**
 $(V_{DD} \text{ and } V_{DDSYN} = 3.0 \text{ to } 3.6 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H)$ 

| Num | Characteristic                                                                                                                                                                                                                              | Symbol      | Min              | Max                  | Unit                                       |
|-----|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-------------|------------------|----------------------|--------------------------------------------|
| 1   | Input High Voltage                                                                                                                                                                                                                          | $V_{IH}$    | 0.7 ( $V_{DD}$ ) | $V_{DD} + 0.3$       | V                                          |
| 2   | Input Low Voltage                                                                                                                                                                                                                           | $V_{IL}$    | $V_{SS} - 0.3$   | 0.2 ( $V_{DD}$ )     | V                                          |
| 3   | Input Hysteresis <sup>1</sup>                                                                                                                                                                                                               | $V_{HYS}$   | 0.5              | —                    | V                                          |
| 4   | Input Leakage Current <sup>2</sup><br>$V_{in} = V_{DD} \text{ or } V_{SS}$ Input-only pins                                                                                                                                                  | $I_{in}$    | -2.5             | 2.5                  | $\mu\text{A}$                              |
| 5   | High Impedance (Off-State) Leakage Current <sup>2</sup><br>$V_{in} = V_{DD} \text{ or } V_{SS}$ All input/output and output pins                                                                                                            | $I_{OZ}$    | -2.5             | 2.5                  | $\mu\text{A}$                              |
| 6   | CMOS Output High Voltage <sup>2, 3</sup><br>$I_{OH} = -10.0 \mu\text{A}$ Group 1, 2, 4 input/output and output pins                                                                                                                         | $V_{OH}$    | $V_{DD} - 0.2$   | —                    | V                                          |
| 7   | CMOS Output Low Voltage <sup>2</sup><br>$I_{OL} = 10.0 \mu\text{A}$ Group 1, 2, 4 input/output and output pins                                                                                                                              | $V_{OL}$    | —                | 0.2                  | V                                          |
| 8   | TTL Compatible Output High Voltage <sup>2, 3</sup><br>$I_{OH} = -0.4 \text{ mA}$ Group 1, 2, 4 input/output and output pins                                                                                                                 | $V_{OH}$    | $V_{DD} - 0.5$   | —                    | V                                          |
| 9   | TTL Compatible Output Low Voltage <sup>2</sup><br>$I_{OL} = 0.8 \text{ mA}$ Group 1 I/O pins, CLKOUT, FREEZE/QUOT, IPIPE/DSO<br>$I_{OL} = 2.6 \text{ mA}$ Group 2 and Group 4 I/O pins, CSBOOT, BG/CS1<br>$I_{OL} = 6.0 \text{ mA}$ Group 3 | $V_{OL}$    | —<br>—<br>—      | 0.4<br>0.4<br>0.4    | V                                          |
| 10  | Three State Control Input High Voltage                                                                                                                                                                                                      | $V_{IHTSC}$ | 2.4 ( $V_{DD}$ ) | 9.1                  | V                                          |
| 11  | Data Bus Mode Select Pull-up Current <sup>4</sup><br>$V_{in} = V_{IL}$<br>$V_{in} = V_{IH}$                                                                                                                                                 | $I_{MSP}$   | —<br>-8          | -95<br>—             | $\mu\text{A}$                              |
| 12  | $V_{DD}$ Supply Current <sup>5</sup><br>Run<br>LPSTOP, external clock input frequency = max $f_{sys}$<br>Run, emulation mode<br>LPSTOP, crystal reference, VCO off (STSIM = 0)                                                              | $I_{DD}$    | —<br>—<br>—<br>— | 56<br>2<br>59<br>350 | mA<br>mA<br>mA<br>$\mu\text{A}$            |
| 13  | Clock Synthesizer Operating Voltage                                                                                                                                                                                                         | $V_{DDSYN}$ | 3.0              | 3.6                  | V                                          |
| 14  | $V_{DDSYN}$ Supply Current<br>External clock, maximum $f_{sys}$<br>Crystal reference, VCO on, maximum $f_{sys}$<br>LPSTOP, crystal reference, VCO off, (STSIM = 0)<br>$V_{DD}$ powered down                                                 | $I_{DDSYN}$ | —<br>—<br>—<br>— | 3<br>1<br>150<br>100 | mA<br>mA<br>$\mu\text{A}$<br>$\mu\text{A}$ |
| 15  | RAM Standby Voltage<br>Specified $V_{DD}$ applied<br>$V_{DD} = V_{SS}$                                                                                                                                                                      | $V_{SB}$    | 0.0<br>2.7       | $V_{DD}$<br>3.6      | V                                          |

Table 5 16.78 MHz DC Characteristics (Continued)

(V<sub>DD</sub> and V<sub>DDSYN</sub> = 3.0 to 3.6 Vdc, V<sub>SS</sub> = 0 Vdc, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>)

| Num | Characteristic                                                                          | Symbol          | Min | Max | Unit |
|-----|-----------------------------------------------------------------------------------------|-----------------|-----|-----|------|
| 16  | RAM Standby Current <sup>6, 7</sup>                                                     | I <sub>SB</sub> | —   | 10  | μA   |
|     | Normal RAM operation V <sub>DD</sub> > V <sub>SB</sub> – 0.5 V                          |                 |     |     |      |
|     | Transient condition V <sub>SB</sub> – 0.5 V ≥ V <sub>DD</sub> ≥ V <sub>SS</sub> + 0.5 V |                 |     |     |      |
|     | Standby operation V <sub>DD</sub> < V <sub>SS</sub> + 0.5 V                             |                 |     |     |      |
| 17  | Power Dissipation <sup>8</sup>                                                          | P <sub>D</sub>  | —   | 212 | mW   |
| 18  | Input Capacitance <sup>2, 9</sup>                                                       | C <sub>in</sub> | —   | 10  | pF   |
|     | All input-only pins                                                                     |                 |     |     |      |
|     | All input/output pins                                                                   |                 |     |     |      |
| 19  | Load Capacitance <sup>2</sup>                                                           | C <sub>L</sub>  | —   | 90  | pF   |
|     | Group 1 I/O Pins, CLKOUT, FREEZE/QUOT, IPIPE/DSO                                        |                 |     |     |      |
|     | Group 2 I/O Pins and CSBOOT, BG/CS1                                                     |                 |     |     |      |
|     | Group 3 I/O Pins                                                                        |                 |     |     |      |
|     | Group 4 I/O Pins                                                                        |                 |     |     |      |

## NOTES:

- Applies to:  
QSM pins  
IRQ[7:1], RESET, EXTAL, TSC, RMC, BKPT/DSCLK, IFETCH/DSI
- Input-Only Pins: TSC, BKPT/DSCLK, RXD  
Output-Only Pins: CSBOOT, BG/CS1, CLKOUT, FREEZE/QUOT, IPIPE/DSO  
Input/Output Pins:  
Group 1: DATA[15:0], IFETCH/DSI  
Group 2: ADDR[23:19]/CS[10:6], FC[2:0]/CS[5:3], DSACK[1:0], AVEC, RMC, DS, AS, SIZ[1:0]  
IRQ[7:1], MODCLK, ADDR[18:0], R/W, BERR, BR/CS0, BGACK/CS2, PCS[3:1], PCS0/SS, TXD  
Group 3: HALT, RESET  
Group 4: MISO, MOSI, SCK
- Does not apply to HALT and RESET because they are open drain pins.  
Does not apply to Port QS[7:0] (TXD, PCS[3:1], PCS0/SS, SCK, MOSI, MISO) in wired-OR mode.
- Current measured at maximum system clock frequency.
- Total operating current is the sum of the appropriate V<sub>DD</sub> supply and V<sub>DDSYN</sub> supply current.
- When V<sub>SB</sub> is more than 0.3V greater than V<sub>DD</sub>, current flows between the V<sub>STBY</sub> and V<sub>DD</sub> pins, which causes standby current to increase toward the maximum condition specification. System noise on the V<sub>DD</sub> and V<sub>STBY</sub> pin can contribute to this condition.
- The SRAM module will not switch into standby mode as long as V<sub>SB</sub> does not exceed V<sub>DD</sub> by more than 0.5 volts. The SRAM array cannot be accessed while the module is in standby mode.
- Power dissipation measured at specified system clock frequency, all modules active. Power dissipation can be calculated using the expression:  
$$P_D = 3.6V (I_{DDSYN} + I_{DD})$$
  
I<sub>DD</sub> includes supply currents for all device modules powered by V<sub>DD</sub> pins
- Input capacitance is periodically sampled rather than 100% tested.

Table 6 16.78 MHz AC Timing

 $(V_{DD} \text{ and } V_{DDSYN} = 3.0 \text{ to } 3.6 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H^1)$ 

| Num    | Characteristic                                                                                                    | Symbol      | Min  | Max   | Unit |
|--------|-------------------------------------------------------------------------------------------------------------------|-------------|------|-------|------|
| F1     | Frequency of Operation                                                                                            | f           | DC   | 16.78 | MHz  |
| 1      | Clock Period                                                                                                      | $t_{cyc}$   | 59.6 | —     | ns   |
| 1A     | ECLK Period                                                                                                       | $t_{Ecyc}$  | 476  | —     | ns   |
| 1B     | External Clock Input Period <sup>2</sup>                                                                          | $t_{xcyc}$  | 59.6 | —     | ns   |
| 2, 3   | Clock Pulse Width                                                                                                 | $t_{CW}$    | 24   | —     | ns   |
| 2A, 3A | ECLK Pulse Width                                                                                                  | $t_{ECW}$   | 236  | —     | ns   |
| 2B, 3B | External Clock Input High/Low Time <sup>2</sup>                                                                   | $t_{xCHL}$  | 29.8 | —     | ns   |
| 4, 5   | CLKOUT Rise and Fall Time                                                                                         | $t_{Crf}$   | —    | 7     | ns   |
| 4A, 5A | Rise and Fall Time (All outputs except CLKOUT)                                                                    | $t_{rf}$    | —    | 8     | ns   |
| 4B, 5B | External Clock Input Rise and Fall Time                                                                           | $t_{xCrf}$  | —    | 4     | ns   |
| 6      | Clock High to ADDR, FC, $\overline{RMC}$ , SIZ Valid                                                              | $t_{CHAV}$  | 0    | 29    | ns   |
| 7      | Clock High to ADDR, Data, FC, $\overline{RMC}$ , SIZ High Impedance                                               | $t_{CHAZx}$ | 0    | 59    | ns   |
| 8      | Clock High to ADDR, FC, $\overline{RMC}$ , SIZ Invalid                                                            | $t_{CHAZn}$ | 0    | —     | ns   |
| 9      | Clock Low to $\overline{AS}$ , $\overline{DS}$ , $\overline{CS}$ Asserted                                         | $t_{CLSA}$  | 0    | 25    | ns   |
| 9A     | $\overline{AS}$ to $\overline{DS}$ or $\overline{CS}$ Asserted (Read) <sup>3</sup>                                | $t_{STSA}$  | -15  | 15    | ns   |
| 9C     | Clock Low to $\overline{IFETCH}$ , $\overline{IPIPE}$ Asserted                                                    | $t_{CLIA}$  | 2    | 22    | ns   |
| 11     | ADDR, FC, $\overline{RMC}$ , SIZ Valid to $\overline{AS}$ , $\overline{CS}$ , (and $\overline{DS}$ Read) Asserted | $t_{AVSA}$  | 15   | —     | ns   |
| 12     | Clock Low to $\overline{AS}$ , $\overline{DS}$ , $\overline{CS}$ Negated                                          | $t_{CLSN}$  | 2    | 29    | ns   |
| 12A    | Clock Low to $\overline{IFETCH}$ , $\overline{IPIPE}$ Negated                                                     | $t_{CLIN}$  | 2    | 29    | ns   |
| 13     | $\overline{AS}$ , $\overline{DS}$ , $\overline{CS}$ Negated to ADDR, FC, SIZ Invalid (Address Hold)               | $t_{SNAI}$  | 15   | —     | ns   |
| 14     | $\overline{AS}$ , $\overline{CS}$ (and $\overline{DS}$ Read) Width Asserted                                       | $t_{SWA}$   | 100  | —     | ns   |
| 14A    | $\overline{DS}$ , $\overline{CS}$ Width Asserted (Write)                                                          | $t_{SWAW}$  | 45   | —     | ns   |
| 14B    | $\overline{AS}$ , $\overline{CS}$ (and $\overline{DS}$ Read) Width Asserted (Fast Cycle)                          | $t_{SWDW}$  | 40   | —     | ns   |
| 15     | $\overline{AS}$ , $\overline{DS}$ , $\overline{CS}$ Width Negated <sup>4</sup>                                    | $t_{SN}$    | 40   | —     | ns   |
| 16     | Clock High to $\overline{AS}$ , $\overline{DS}$ , $\overline{R/W}$ High Impedance                                 | $t_{CHSZ}$  | —    | 59    | ns   |
| 17     | $\overline{AS}$ , $\overline{DS}$ , $\overline{CS}$ Negated to $\overline{R/W}$ High                              | $t_{SNRN}$  | 15   | —     | ns   |
| 18     | Clock High to $\overline{R/W}$ High                                                                               | $t_{CHRH}$  | 0    | 29    | ns   |
| 20     | Clock High to $\overline{R/W}$ Low                                                                                | $t_{CHRL}$  | 0    | 29    | ns   |
| 21     | $\overline{R/W}$ High to $\overline{AS}$ , $\overline{CS}$ Asserted                                               | $t_{RAAA}$  | 15   | —     | ns   |
| 22     | $\overline{R/W}$ Low to $\overline{DS}$ , $\overline{CS}$ Asserted (Write)                                        | $t_{RASA}$  | 70   | —     | ns   |
| 23     | Clock High to Data Out Valid                                                                                      | $t_{CHDO}$  | —    | 29    | ns   |

**Table 6 16.78 MHz AC Timing (Continued)**
 $(V_{DD} \text{ and } V_{DDSYN} = 3.0 \text{ to } 3.6 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H^1)$ 

| Num | Characteristic                                                                                                                                              | Symbol       | Min | Max | Unit      |
|-----|-------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------|-----|-----|-----------|
| 24  | Data Out Valid to Negating Edge of $\overline{AS}$ , $\overline{CS}$ (Fast Write Cycle)                                                                     | $t_{DVASN}$  | 15  | —   | ns        |
| 25  | $\overline{DS}$ , $\overline{CS}$ Negated to Data Out Invalid (Data Out Hold)                                                                               | $t_{SND OI}$ | 15  | —   | ns        |
| 26  | Data Out Valid to $\overline{DS}$ , $\overline{CS}$ Asserted (Write)                                                                                        | $t_{DVSA}$   | 15  | —   | ns        |
| 27  | Data In Valid to Clock Low (Data Setup)                                                                                                                     | $t_{DICL}$   | 5   | —   | ns        |
| 27A | Late $\overline{BERR}$ , $\overline{HALT}$ Asserted to Clock Low (Setup Time)                                                                               | $t_{BELCL}$  | 20  | —   | ns        |
| 28  | $\overline{AS}$ , $\overline{DS}$ Negated to $\overline{DSACK}[1:0]$ , $\overline{BERR}$ , $\overline{HALT}$ , $\overline{AVEC}$ Negated                    | $t_{SNDN}$   | 0   | 80  | ns        |
| 29  | $\overline{DS}$ , $\overline{CS}$ Negated to Data In Invalid (Data In Hold) <sup>5</sup>                                                                    | $t_{SNDI}$   | 0   | —   | ns        |
| 29A | $\overline{DS}$ , $\overline{CS}$ Negated to Data In High Impedance <sup>5, 6</sup>                                                                         | $t_{SHDI}$   | —   | 55  | ns        |
| 30  | CLKOUT Low to Data In Invalid (Fast Cycle Hold) <sup>5</sup>                                                                                                | $t_{CLDI}$   | 10  | —   | ns        |
| 30A | CLKOUT Low to Data In High Impedance <sup>5</sup>                                                                                                           | $t_{CLDH}$   | —   | 90  | ns        |
| 31  | $\overline{DSACK}[1:0]$ Asserted to Data In Valid <sup>7</sup>                                                                                              | $t_{DADI}$   | —   | 50  | ns        |
| 33  | Clock Low to $\overline{BG}$ Asserted/Negated                                                                                                               | $t_{CLBAN}$  | —   | 29  | ns        |
| 35  | $\overline{BR}$ Asserted to $\overline{BG}$ Asserted ( $\overline{RMC}$ not Asserted) <sup>8</sup>                                                          | $t_{BRAGA}$  | 1   | —   | $t_{cyc}$ |
| 37  | $\overline{BGACK}$ Asserted to $\overline{BG}$ Negated                                                                                                      | $t_{GAGN}$   | 1   | 2   | $t_{cyc}$ |
| 39  | $\overline{BG}$ Width Negated                                                                                                                               | $t_{GH}$     | 2   | —   | $t_{cyc}$ |
| 39A | $\overline{BG}$ Width Asserted                                                                                                                              | $t_{GA}$     | 1   | —   | $t_{cyc}$ |
| 46  | $R/\overline{W}$ Width Asserted (Write or Read)                                                                                                             | $t_{RWA}$    | 150 | —   | ns        |
| 46A | $R/\overline{W}$ Width Asserted (Fast Write or Read Cycle)                                                                                                  | $t_{RWAS}$   | 90  | —   | ns        |
| 47A | Asynchronous Input Setup Time<br>$\overline{BR}$ , $\overline{BGACK}$ , $\overline{DSACK}[1:0]$ , $\overline{BERR}$ , $\overline{AVEC}$ , $\overline{HALT}$ | $t_{AIST}$   | 5   | —   | ns        |
| 47B | Asynchronous Input Hold Time                                                                                                                                | $t_{AIHT}$   | 15  | —   | ns        |
| 48  | $\overline{DSACK}[1:0]$ Asserted to $\overline{BERR}$ , $\overline{HALT}$ Asserted <sup>9</sup>                                                             | $t_{DABA}$   | —   | 30  | ns        |
| 53  | Data Out Hold from Clock High                                                                                                                               | $t_{DOCH}$   | 0   | —   | ns        |
| 54  | Clock High to Data Out High Impedance                                                                                                                       | $t_{CHDH}$   | —   | 28  | ns        |
| 55  | $R/\overline{W}$ Asserted to Data Bus Impedance Change                                                                                                      | $t_{RADC}$   | 40  | —   | ns        |
| 70  | Clock Low to Data Bus Driven (Show Cycle)                                                                                                                   | $t_{SCLDD}$  | 0   | 29  | ns        |
| 71  | Data Setup Time to Clock Low (Show Cycle)                                                                                                                   | $t_{SCLDS}$  | 15  | —   | ns        |
| 72  | Data Hold from Clock Low (Show Cycle)                                                                                                                       | $t_{SCLDH}$  | 10  | —   | ns        |
| 73  | $\overline{BKPT}$ Input Setup Time                                                                                                                          | $t_{BKST}$   | 15  | —   | ns        |
| 74  | $\overline{BKPT}$ Input Hold Time                                                                                                                           | $t_{BKHT}$   | 10  | —   | ns        |
| 75  | Mode Select Setup Time                                                                                                                                      | $t_{MSS}$    | 20  | —   | $t_{cyc}$ |
| 76  | Mode Select Hold Time                                                                                                                                       | $t_{MSH}$    | 0   | —   | ns        |

Table 6 16.78 MHz AC Timing (Continued)

 $(V_{DD} \text{ and } V_{DDSYN} = 3.0 \text{ to } 3.6 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H)^1$ 

| Num | Characteristic                                         | Symbol     | Min | Max | Unit      |
|-----|--------------------------------------------------------|------------|-----|-----|-----------|
| 77  | $\overline{\text{RESET}}$ Assertion Time <sup>10</sup> | $t_{RSTA}$ | 4   | —   | $t_{cyc}$ |
| 78  | $\overline{\text{RESET}}$ Rise Time <sup>11, 12</sup>  | $t_{RSTR}$ | —   | 10  | $t_{cyc}$ |

## NOTES:

1. All AC timing is shown with respect to 2.0 V to 0.8 V levels unless otherwise noted.
2. When an external clock is used, minimum high and low times are based on a 50% duty cycle. The minimum allowable  $t_{xcyc}$  period is reduced when the duty cycle of the external clock varies. The relationship between external clock input duty cycle and minimum  $t_{xcyc}$  is expressed:  
Minimum  $t_{xcyc}$  period = minimum  $t_{xchl}$  / (50% – external clock input duty cycle tolerance).
3. Specification 9A is the worst-case skew between  $\overline{\text{AS}}$  and  $\overline{\text{DS}}$  or  $\overline{\text{CS}}$ . The amount of skew depends on the relative loading of these signals. When loads are kept within specified limits, skew will not cause  $\overline{\text{AS}}$  and  $\overline{\text{DS}}$  to fall outside the limits shown in specification 9.
4. If multiple chip-selects are used,  $\overline{\text{CS}}$  width negated (specification 15) applies to the time from the negation of a heavily loaded chip-select to the assertion of a lightly loaded chip select. The  $\overline{\text{CS}}$  width negated specification between multiple chip-selects does not apply to chip selects being used for synchronous ECLK cycles.
5. Hold times are specified with respect to  $\overline{\text{DS}}$  or  $\overline{\text{CS}}$  on asynchronous reads and with respect to CLKOUT on fast cycle reads. The user is free to use either hold time.
6. Maximum value is equal to  $(t_{cyc} / 2) + 25 \text{ ns}$ .
7. If the asynchronous setup time (specification 47A) requirements are satisfied, the  $\overline{\text{DSACK}}[1:0]$  low to data setup time (specification 31) and  $\overline{\text{DSACK}}[1:0]$  low to  $\overline{\text{BERR}}$  low setup time (specification 48) can be ignored. The data must only satisfy the data-in to clock low setup time (specification 27) for the following clock cycle.  $\overline{\text{BERR}}$  must satisfy only the late  $\overline{\text{BERR}}$  low to clock low setup time (specification 27A) for the following clock cycle.
8. To ensure coherency during every operand transfer,  $\overline{\text{BG}}$  is not asserted in response to  $\overline{\text{BR}}$  until after all cycles of the current operand transfer are complete.
9. In the absence of  $\overline{\text{DSACK}}[1:0]$ ,  $\overline{\text{BERR}}$  is an asynchronous input using the asynchronous setup time (specification 47A).
10. After external  $\overline{\text{RESET}}$  negation is detected, a short transition period (approximately 2)  $t_{cyc}$  elapses, then the SIM drives  $\overline{\text{RESET}}$  low for 512  $t_{cyc}$ .
11. External assertion of the  $\overline{\text{RESET}}$  input can overlap internally-generated resets. To insure that an external reset is recognized in all cases,  $\overline{\text{RESET}}$  must be asserted for at least 590 CLKOUT cycles.
12. External logic must pull  $\overline{\text{RESET}}$  high during this period in order for normal MCU operation to begin.

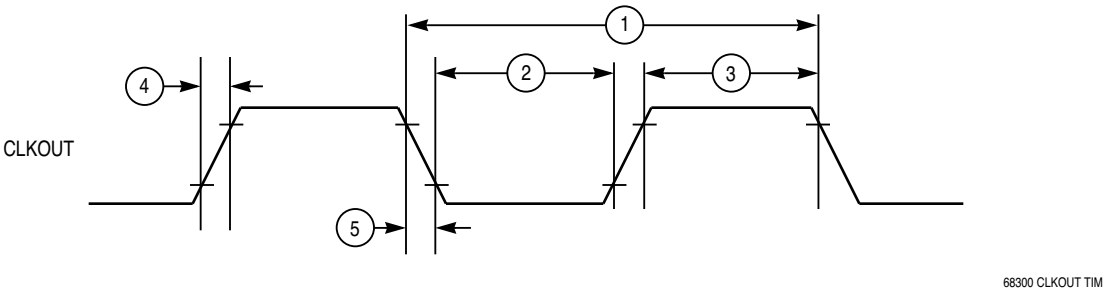


Figure 1 CLKOUT Output Timing Diagram

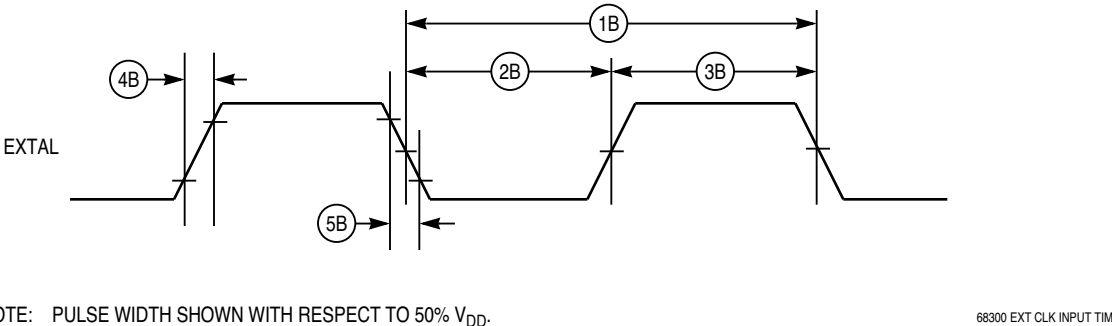


Figure 2 External Clock Input Timing Diagram

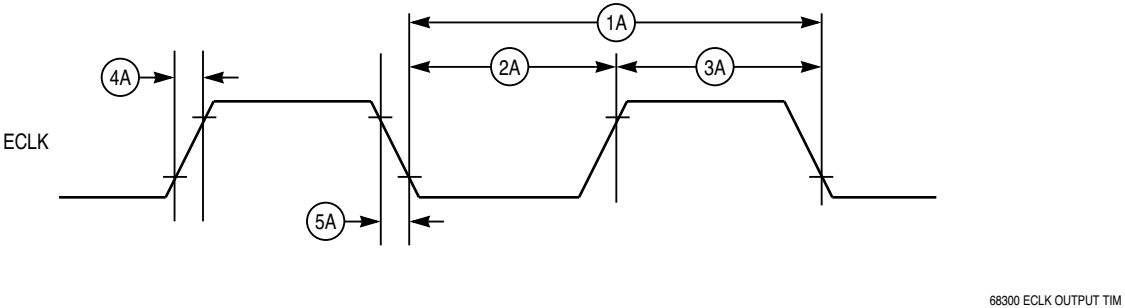
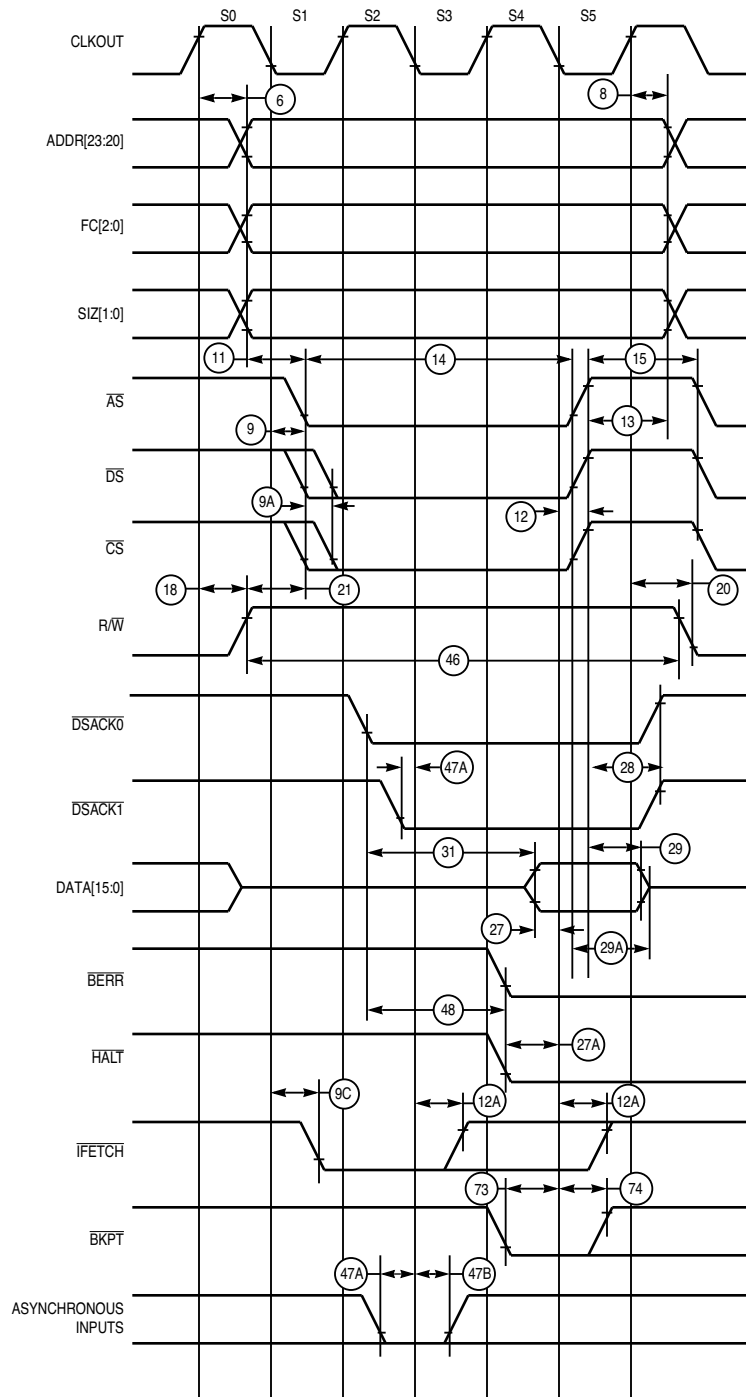
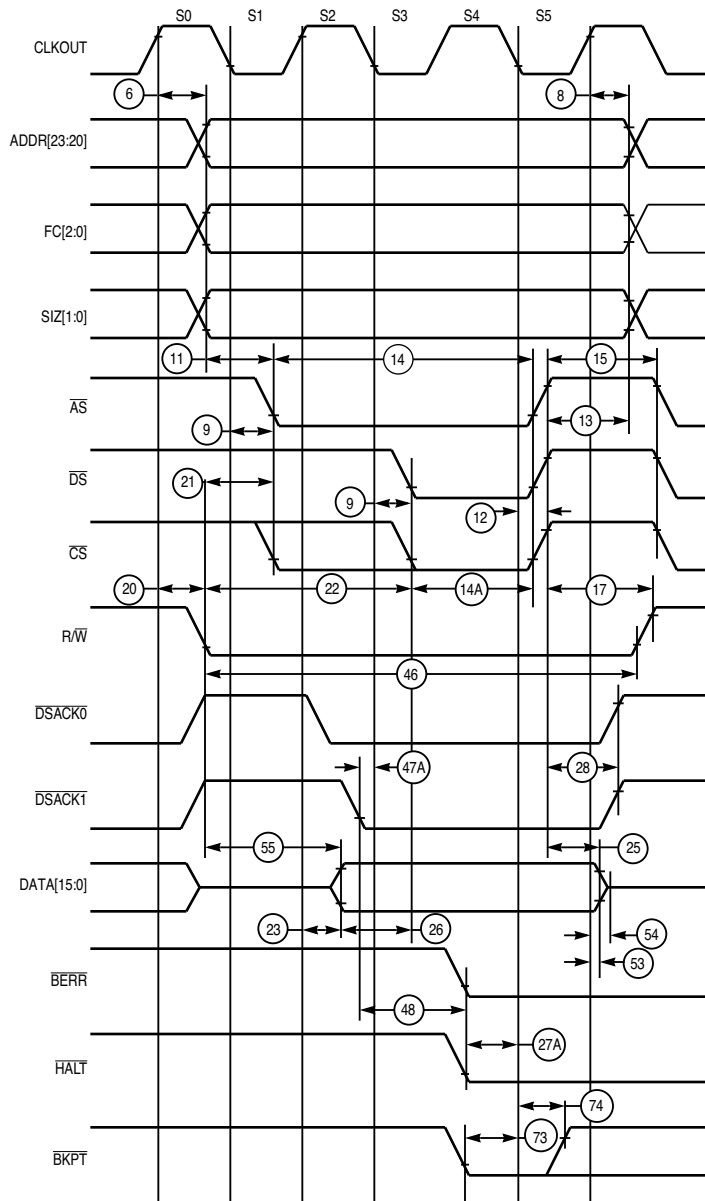


Figure 3 ECLK Output Timing Diagram



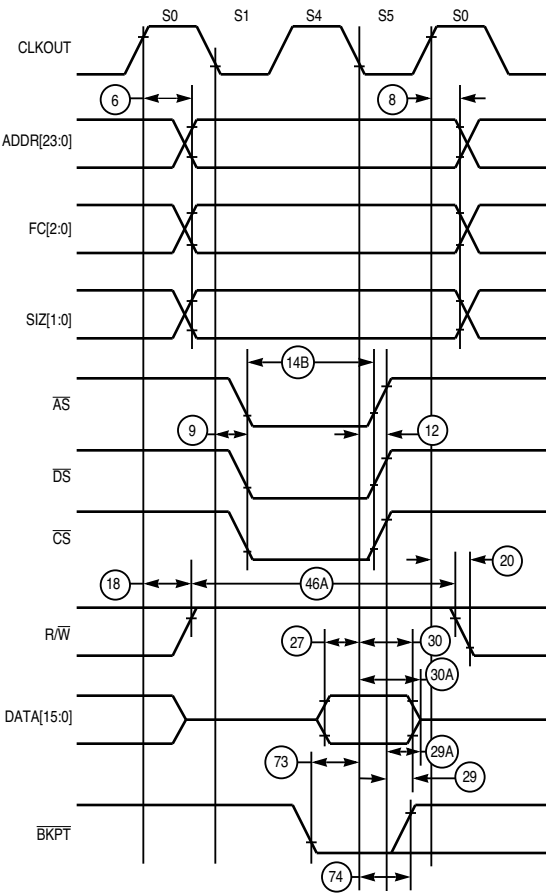
68300 RD CYC TIM

**Figure 4 Read Cycle Timing Diagram**



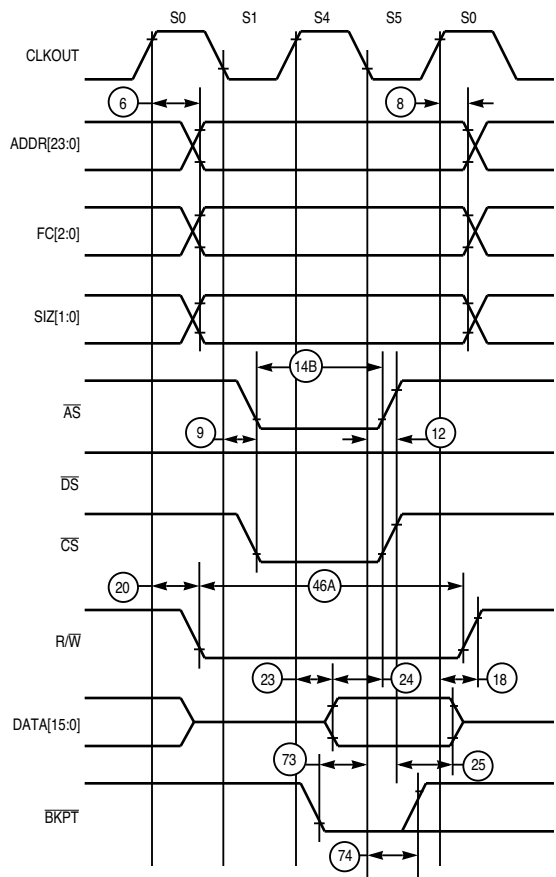
68300 WR CYC TIM

**Figure 5 Write Cycle Timing Diagram**



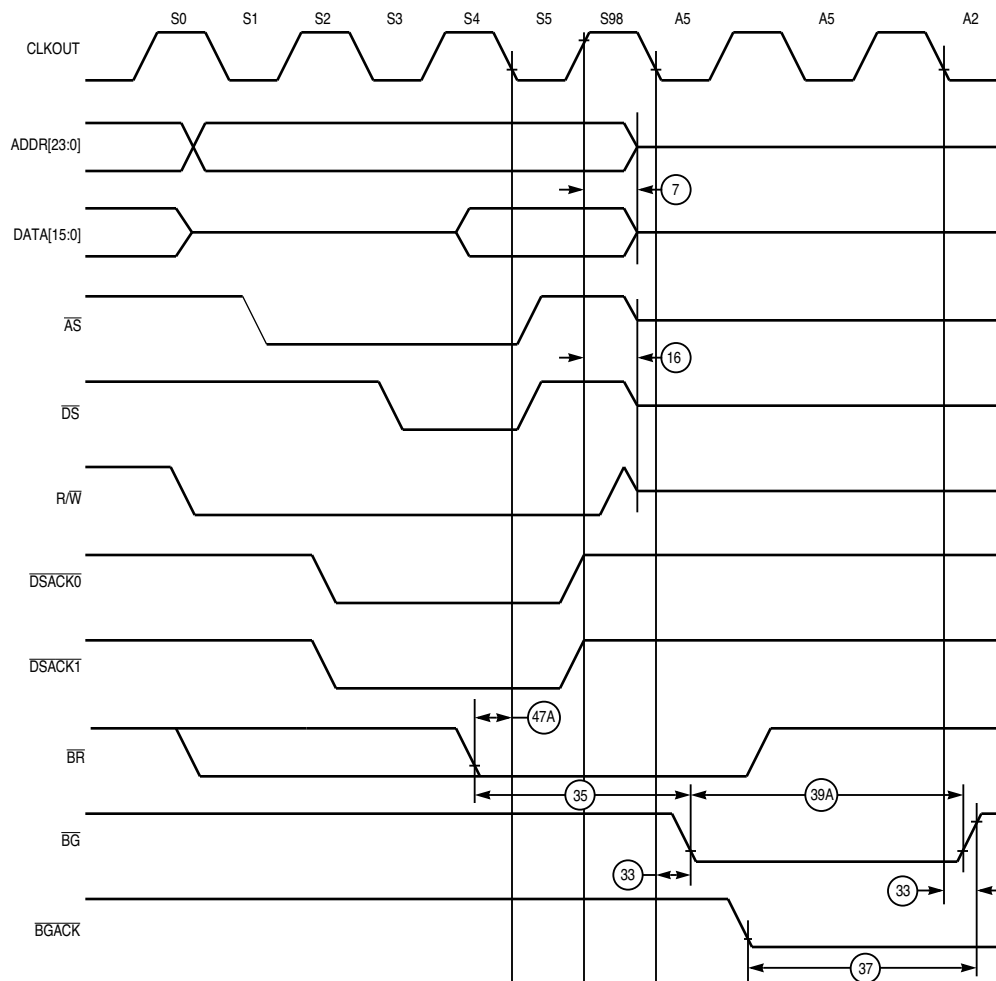
68300 FAST RD CYC TIM

Figure 6 Fast Termination Read Cycle Timing Diagram



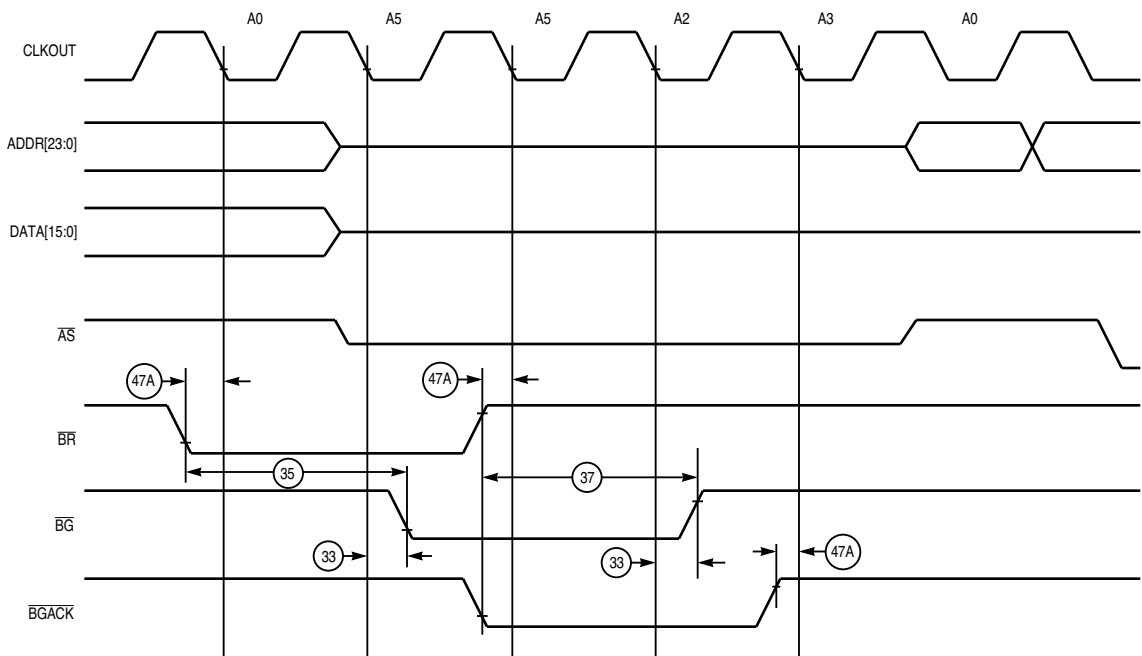
68300 FAST WR CYC TIM

Figure 7 Fast Termination Write Cycle Timing Diagram



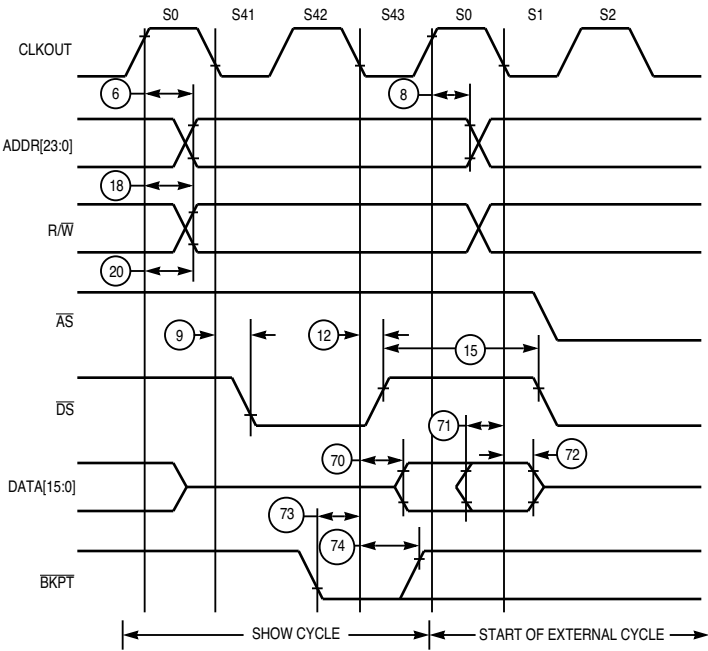
68300 BUS ARB TIM

**Figure 8 Bus Arbitration Timing Diagram — Active Bus Case**



68300 BUS ARB TIM IDLE

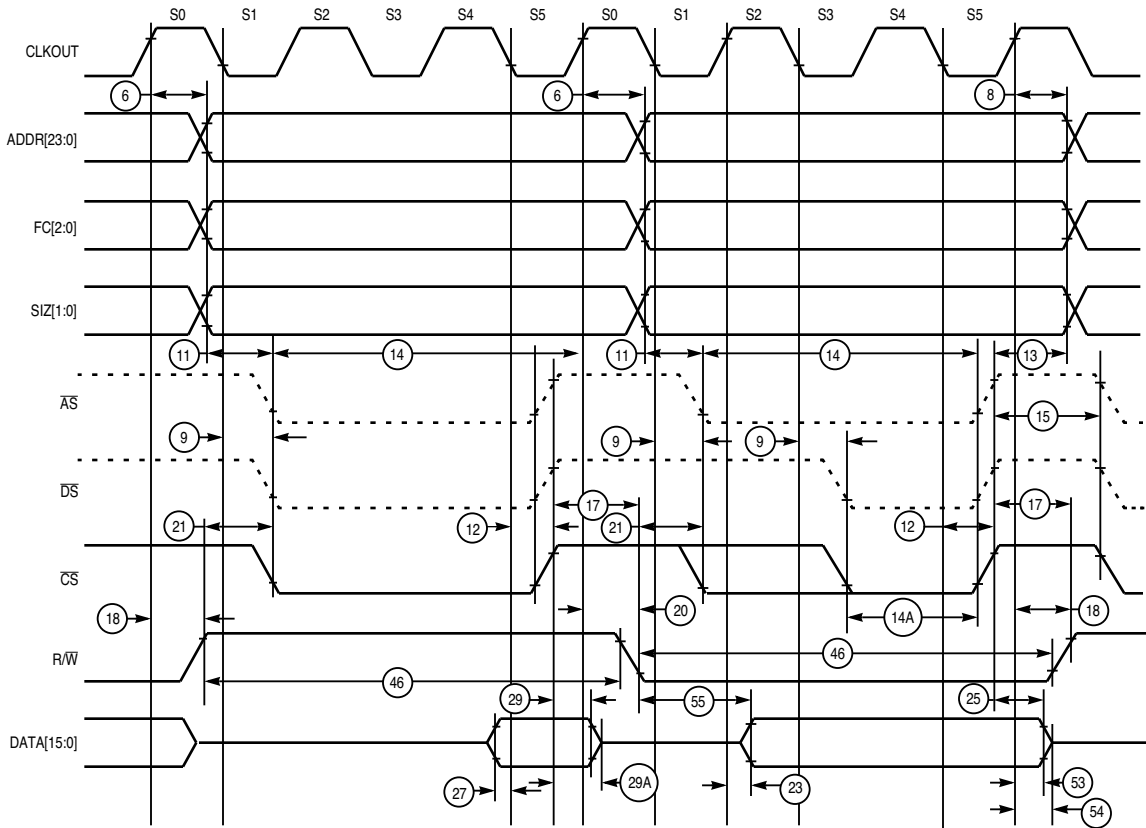
Figure 9 Bus Arbitration Timing Diagram — Idle Bus Case



NOTE:  
SHOW CYCLES CAN STRETCH DURING CLOCK PHASE S42 WHEN BUS ACCESSES TAKE LONGER THAN TWO CYCLES DUE TO IMB MODULE WAIT-STATE INSERTION.

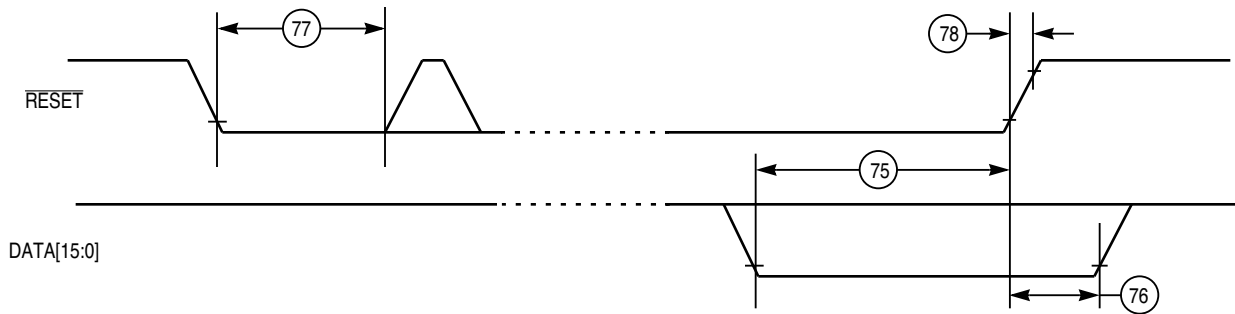
68300 SHW CYC TIM

Figure 10 Show Cycle Timing Diagram



68300 CHIP SEL TIM

Figure 11 Chip-Select Timing Diagram



68300 RST/MODE SEL TIM

Figure 12 Reset and Mode Select Timing Diagram

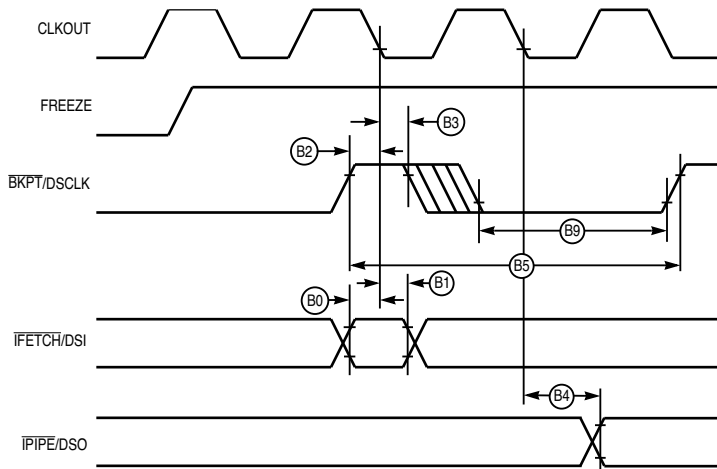
**Table 7 Background Debugging Mode Timing**

( $V_{DD}$  and  $V_{DDSYN} = 3.0$  to  $3.6$  Vdc,  $V_{SS} = 0$  Vdc,  $T_A = T_L$  to  $T_H$ )<sup>1</sup>

| Num | Characteristic                                    | Symbol       | Min | Max | Unit      |
|-----|---------------------------------------------------|--------------|-----|-----|-----------|
| B0  | DSI Input Setup Time                              | $t_{DSISU}$  | 15  | —   | ns        |
| B1  | DSI Input Hold Time                               | $t_{DSIH}$   | 10  | —   | ns        |
| B2  | DSCLK Setup Time                                  | $t_{DSCSU}$  | 15  | —   | ns        |
| B3  | DSCLK Hold Time                                   | $t_{DSCH}$   | 10  | —   | ns        |
| B4  | DSO Delay Time                                    | $t_{DSOD}$   | —   | 25  | ns        |
| B5  | DSCLK Cycle Time                                  | $t_{DSCCYC}$ | 2   | —   | $t_{cyc}$ |
| B6  | CLKOUT Low to FREEZE Asserted/Negated             | $t_{FRZAN}$  | —   | 50  | ns        |
| B7  | CLKOUT High to $\overline{IFETCH}$ High Impedance | $t_{IPZ}$    | —   | 50  | ns        |
| B8  | CLKOUT High to $\overline{IFETCH}$ Valid          | $t_{IP}$     | —   | 50  | ns        |
| B9  | DSCLK Low Time                                    | $t_{DSCLO}$  | 1   | —   | $t_{cyc}$ |

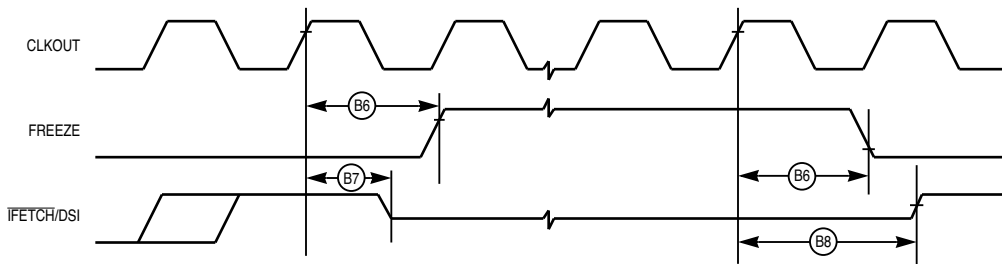
**NOTES:**

1. All AC timing is shown with respect to 20%  $V_{DD}$  and 70%  $V_{DD}$  levels unless otherwise noted.



68300 BKGD DBM SER COM TIM

**Figure 13 BDM Serial Communication Timing Diagram**



68300 BDM FRZ TIM

**Figure 14 BDM Freeze Assertion Timing Diagram**

Table 8 ECLK Bus Timing

$$(V_{DD} \text{ and } V_{DDSYN} = 3.0 \text{ to } 3.6 \text{ Vdc}, V_{SS} = 0 \text{ Vdc}, T_A = T_L \text{ to } T_H)^1$$

| Num | Characteristic                                             | Symbol      | Min | Max | Unit      |
|-----|------------------------------------------------------------|-------------|-----|-----|-----------|
| E1  | ECLK Low to Address Valid <sup>2</sup>                     | $t_{EAD}$   | —   | 60  | ns        |
| E2  | ECLK Low to Address Hold                                   | $t_{EAH}$   | 15  | —   | ns        |
| E3  | ECLK Low to $\overline{CS}$ Valid ( $\overline{CS}$ Delay) | $t_{ECS D}$ | —   | 150 | ns        |
| E4  | ECLK Low to $\overline{CS}$ Hold                           | $t_{ECS H}$ | 15  | —   | ns        |
| E5  | $\overline{CS}$ Negated Width                              | $t_{ECS N}$ | 30  | —   | ns        |
| E6  | Read Data Setup Time                                       | $t_{EDSR}$  | 30  | —   | ns        |
| E7  | Read Data Hold Time                                        | $t_{EDHR}$  | 5   | —   | ns        |
| E8  | ECLK Low to Data High Impedance                            | $t_{EDHZ}$  | —   | 60  | ns        |
| E9  | $\overline{CS}$ Negated to Data Hold (Read)                | $t_{ECDH}$  | 0   | —   | ns        |
| E10 | $\overline{CS}$ Negated to Data High Impedance             | $t_{ECDZ}$  | —   | 1   | $t_{cyc}$ |
| E11 | ECLK Low to Data Valid (Write)                             | $t_{EDDW}$  | —   | 2   | $t_{cyc}$ |
| E12 | ECLK Low to Data Hold (Write)                              | $t_{EDHW}$  | 15  | —   | ns        |
| E13 | Address Access Time (Read) <sup>3</sup>                    | $t_{EACC}$  | 386 | —   | ns        |
| E14 | Chip-Select Access Time (Read) <sup>4</sup>                | $t_{EACS}$  | 296 | —   | ns        |
| E15 | Address Setup Time                                         | $t_{EAS}$   | 1/2 | —   | $t_{cyc}$ |

## NOTES:

1. All AC timing is shown with respect to 20%  $V_{DD}$  and 70%  $V_{DD}$  levels unless otherwise noted.
2. When previous bus cycle is not an ECLK cycle, the address may be valid before ECLK goes low.
3. Address access time =  $t_{E_{cyc}} - t_{EAD} - t_{EDSR}$ .
4. Chip select access time =  $t_{E_{cyc}} - t_{ECS D} - t_{EDSR}$ .

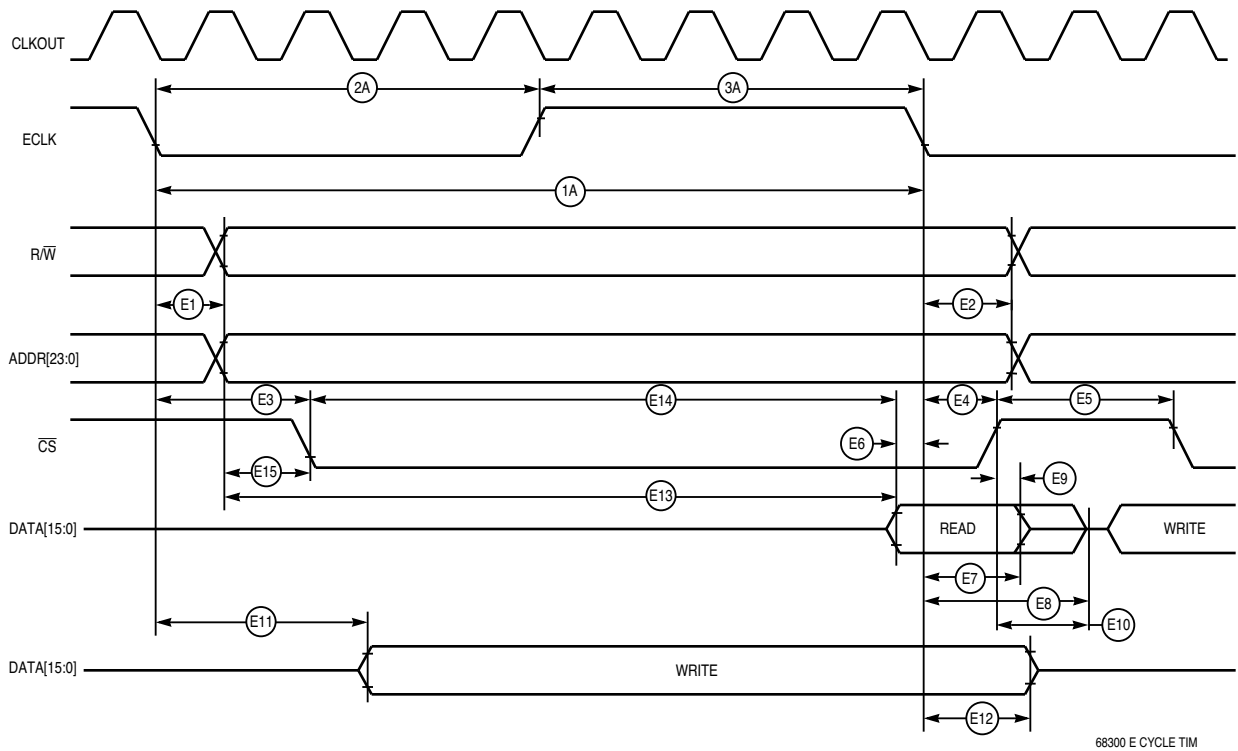


Figure 15 ECLK Timing Diagram

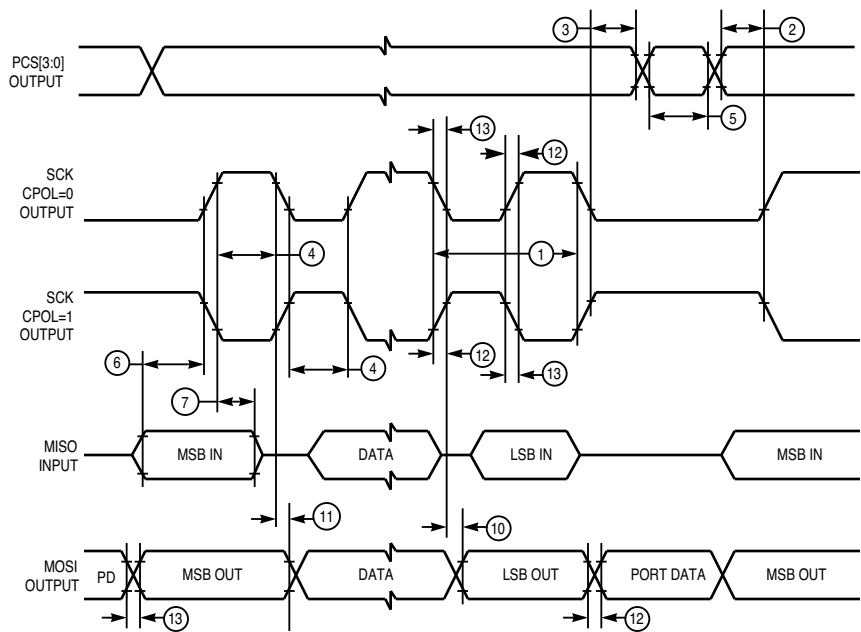
Table 9 QSPI Timing

(V<sub>DD</sub> and V<sub>DDSYN</sub> = 3.0 to 3.6 Vdc, V<sub>SS</sub> = 0 Vdc, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>, 100 pF load on all QSPI pins)<sup>1</sup>

| Num | Function                                                                 | Symbol                             | Min                                               | Max                       | Unit                                 |
|-----|--------------------------------------------------------------------------|------------------------------------|---------------------------------------------------|---------------------------|--------------------------------------|
| 1   | Operating Frequency<br>Master<br>Slave                                   | f <sub>op</sub>                    | DC<br>DC                                          | 1/4<br>1/4                | f <sub>sys</sub><br>f <sub>sys</sub> |
| 2   | Cycle Time<br>Master<br>Slave                                            | t <sub>qcy</sub>                   | 4<br>4                                            | 510<br>—                  | t <sub>cyc</sub><br>t <sub>cyc</sub> |
| 3   | Enable Lead Time<br>Master<br>Slave                                      | t <sub>lead</sub>                  | 2<br>2                                            | 128<br>—                  | t <sub>cyc</sub><br>t <sub>cyc</sub> |
| 4   | Enable Lag Time<br>Master<br>Slave                                       | t <sub>lag</sub>                   | —<br>2                                            | 1/2<br>—                  | SCK<br>t <sub>cyc</sub>              |
| 5   | Clock (SCK) High or Low Time<br>Master<br>Slave <sup>2</sup>             | t <sub>sw</sub>                    | 2 t <sub>cyc</sub> – 60<br>2 t <sub>cyc</sub> – n | 255 t <sub>cyc</sub><br>— | ns<br>ns                             |
| 6   | Sequential Transfer Delay<br>Master<br>Slave (Does Not Require Deselect) | t <sub>td</sub>                    | 17<br>13                                          | 8192<br>—                 | t <sub>cyc</sub><br>t <sub>cyc</sub> |
| 7   | Data Setup Time (Inputs)<br>Master<br>Slave                              | t <sub>su</sub>                    | 30<br>20                                          | —<br>—                    | ns<br>ns                             |
| 8   | Data Hold Time (Inputs)<br>Master<br>Slave                               | t <sub>hi</sub>                    | 0<br>20                                           | —<br>—                    | ns<br>ns                             |
| 9   | Slave Access Time                                                        | t <sub>a</sub>                     | —                                                 | 1                         | t <sub>cyc</sub>                     |
| 10  | Slave MISO Disable Time                                                  | t <sub>dis</sub>                   | —                                                 | 2                         | t <sub>cyc</sub>                     |
| 11  | Data Valid (after SCK Edge)<br>Master<br>Slave                           | t <sub>v</sub>                     | —<br>—                                            | 50<br>50                  | ns<br>ns                             |
| 12  | Data Hold Time (Outputs)<br>Master<br>Slave                              | t <sub>ho</sub>                    | 0<br>0                                            | —<br>—                    | ns<br>ns                             |
| 13  | Rise Time<br>Input<br>Output                                             | t <sub>ri</sub><br>t <sub>ro</sub> | —<br>—                                            | 2<br>30                   | μs<br>ns                             |
| 14  | Fall Time<br>Input<br>Output                                             | t <sub>fi</sub><br>t <sub>fo</sub> | —<br>—                                            | 2<br>30                   | μs<br>ns                             |

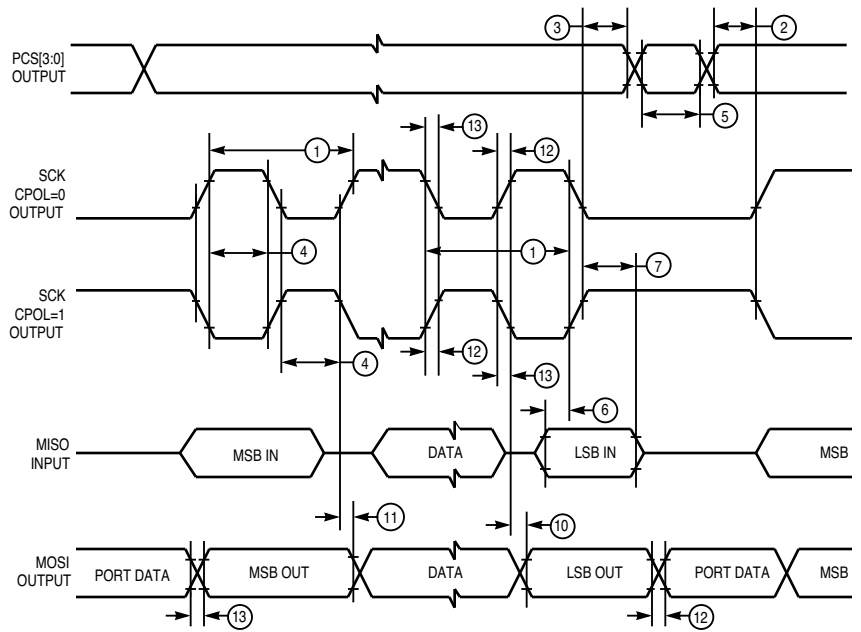
## NOTES:

1. All AC timing is shown with respect to 20% V<sub>DD</sub> and 70% V<sub>DD</sub> levels unless otherwise noted.
2. For high time, n = External SCK rise time; for low time, n = External SCK fall time.



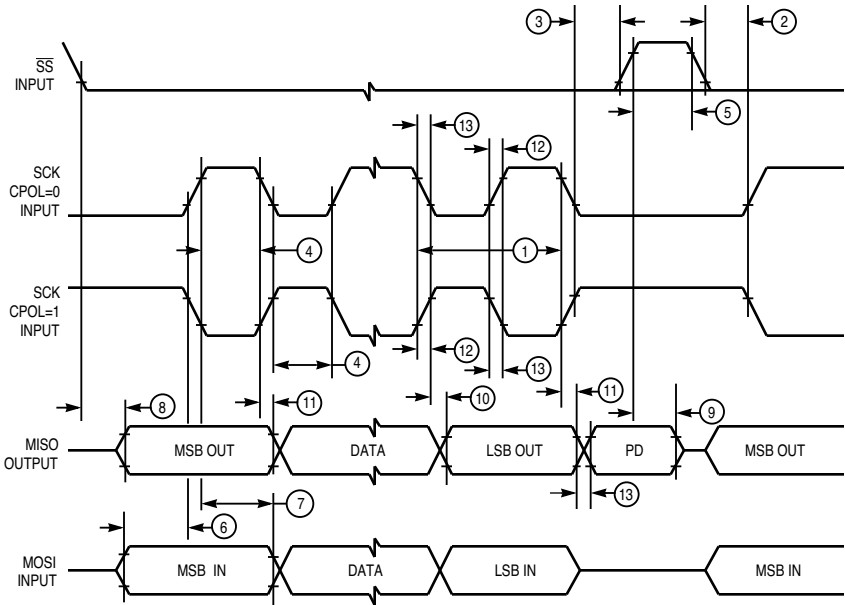
68300 QSPI MAST CPHA0

**Figure 16 QSPI Timing — Master, CPHA = 0**



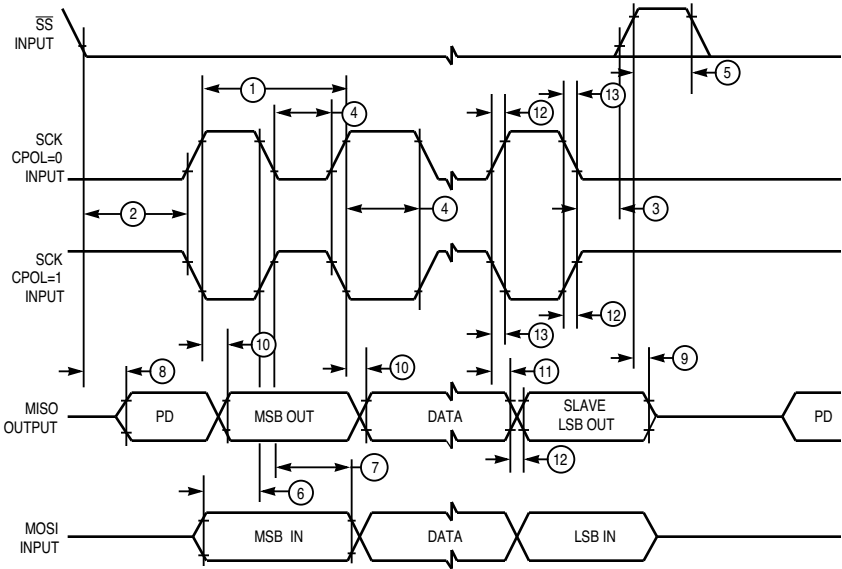
68300 QSPI MAST CPHA1

**Figure 17 QSPI Timing — Master, CPHA = 1**



68300 QSPI SLV CPHA0

Figure 18 QSPI Timing — Slave, CPHA = 0



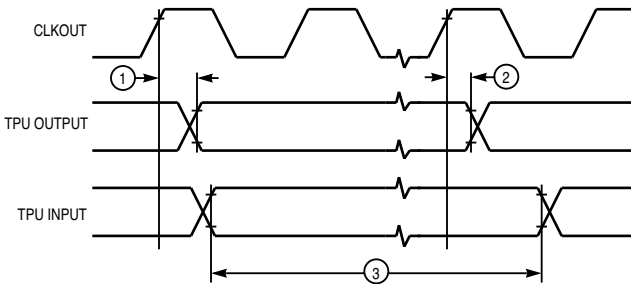
68300 QSPI SLV CPHA1

Figure 19 QSPI Timing — Slave, CPHA = 1

Table 10 Time Processor Unit Timing  
(V<sub>DD</sub> and V<sub>DDA</sub> = 3.0 to 3.6Vdc, V<sub>SS</sub> = 0 Vdc, T<sub>A</sub> = T<sub>L</sub> to T<sub>H</sub>)<sup>1</sup>

| Num | Parameter                                                  | Symbol             | Min | Max | Unit             |
|-----|------------------------------------------------------------|--------------------|-----|-----|------------------|
| 1   | CLKOUT High to TPU Output Channel Valid <sup>2, 3, 4</sup> | t <sub>CHTOV</sub> | 2   | 23  | ns               |
| 2   | CLKOUT High to TPU Output Channel Hold                     | t <sub>CHTOH</sub> | 0   | 20  | ns               |
| 3   | TPU Input Channel Pulse Width                              | t <sub>TIPW</sub>  | 4   | —   | t <sub>cyc</sub> |

- NOTES:
- 1. AC Timing is shown with respect to 20% V<sub>DD</sub> and 70% V<sub>DD</sub> levels.
  - 2. Timing not valid for external T2CLK input.
  - 3. Maximum load capacitance for CLKOUT pin is 90 pF.
  - 4. Maximum load capacitance for TPU output pins is 100 pF.



TPU I/O TIM

Figure 20 TPU Timing Diagram

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